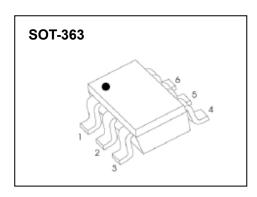


JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOT-363 Plastic-Encapsulate MOSFETS

CJ3439KDW N channel+P Channel MOSFET

V _{(BR)DSS}	R _{DS(on)} MAX	I _D
	380mΩ@4.5V	
20 V	450mΩ@2.5V	0.75A
	800mΩ@1.8V	
	520mΩ@-4.5V	
-20∨	700mΩ@-2.5V	-0.66A
	950mΩ(TYP)@-1.8V	



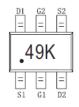
FEATURE

- Surface Mount Package
- Low R_{DS}(on)
- Operated at Low Logic Level Gate Drive
- ESD Protected Gate
- Including a N-ch CJ3134K and a P-ch CJ3139K (independently) In a Package

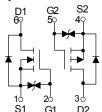
APPLICATION

- Load/ Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

MARKING



Equivalent Circuit



ABSOLUTE MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
N-MOSFET			
Drain-Source Voltage	V _{DS}	20	V
Typical Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current (note 1)	I _D	0.75	Α
Pulsed Drain Current (tp=10us)	I _{DM}	1.8	Α
P-MOSFET	•		
Drain-Source Voltage	V _{DS}	-20	V
Typical Gate-Source Voltage	V_{GS}	±12	V
Continuous Drain Current (note 1)	I _D	-0.66	Α
Pulsed Drain Current (tp=10us)	I _{DM}	-1.2	Α
Temperature and Thermal Resistance			
Thermal Resistance from Junction to Ambient (note 1)	$R_{\theta JA}$	833	°C/W
Junction Temperature	TJ	150	°C
Storage Temperature	T _{STG}	-55~+150	°C
Lead Temperature for Soldering Purposes(1/8" from case for 10 s)	TL	260	°C

MOSFET ELECTRICAL CHARACTERISTICS

N-ch MOSFET ELECTRICAL CHARACTERISTICS(T_a=25℃ unless otherwise noted)

Parameter	Parameter Symbol Test Condition		Min	Тур	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	V(BR)DSS	V _G S = 0V, I _D =250µA	20			V
Zero gate voltage drain current	IDSS	V _{DS} =20V,V _{GS} = 0V			1	μΑ
Gate-body leakage current	Igss	V _{GS} =±10V, V _{DS} = 0V			±20	uA
Gate threshold voltage (note 2)	VGS(th)	V _{DS} =V _{GS} , I _D =250μA	0.35		1.1	V
Drain accurac on register accurate 2)	D	V _{GS} =4.5V, I _D =0.65A			380	mΩ
Drain-source on-resistance(note 2)	RDS(on)	V _{GS} =2.5V, I _D =0.55A			450	mΩ
		V _{GS} =1.8V, I _D =0.45A			800	mΩ
Forward tranconductance(note 2)	g FS	V _{DS} =10V, I _D =0.8A		1.6		S
Diode forward voltage	V_{SD}	I _S =0.15A, V _{GS} = 0V			1.2	V
DYNAMIC CHARACTERISTICS (note	4)					
Input Capacitance	C _{iss}			79	120	pF
Output Capacitance	Coss	V _{DS} =16V,V _{GS} =0V,f =1MHz		13	20	pF
Reverse Transfer Capacitance	C_{rss}			9	15	pF
SWITCHING CHARACTERISTICS (not	e 3,4)					
Turn-on delay time	t d(on)			6.7		ns
Turn-on rise time	tr	V _{GS} =4.5V,V _{DS} =10V,		4.8		ns
Turn-off delay time	td(off)	$I_D=500$ mA, $R_{GEN}=10\Omega$		17.3		ns
Turn-off fall time	tf			7.4		ns

P-ch MOSFET ELECTRICAL CHARACTERISTICS(T_a=25°C unless otherwise noted)

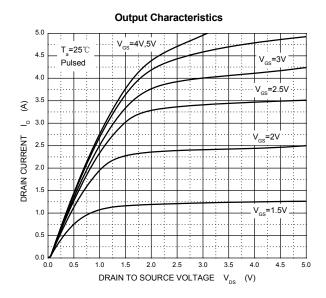
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit			
STATIC CHARACTERISTICS									
Drain-source breakdown voltage	V(BR)DSS	V _G S = 0V, I _D =-250µA	-20			V			
Zero gate voltage drain current	IDSS	V _{DS} =-20V,V _{GS} = 0V			-1	μΑ			
Gate-body leakage current	Igss	V _{GS} =±10V, V _{DS} = 0V			±20	uA			
Gate threshold voltage (note 2)	VGS(th)	V _{DS} =V _{GS} , I _D =-250μA	-0.35		-1.1	V			
Dunin course on registeres (note 2)	D	V _{GS} =-4.5V, I _D =-1A			520	mΩ			
Drain-source on-resistance(note 2)	RDS(on)	V _{GS} =-2.5V, I _D =-0.8A			700	mΩ			
		V _{GS} =-1.8V, I _D =-0.5A		950		mΩ			
Forward tranconductance(note 2)	g FS	V _{DS} =-10V, I _D =-0.54A		1.2		S			
Diode forward voltage	V _{SD}	I _S =-0.5A, V _{GS} = 0V			-1.2	V			
DYNAMIC CHARACTERISTICS (note	4)								
Input Capacitance	C _{iss}			113	170	рF			
Output Capacitance	Coss	V _{DS} =-16V,V _{GS} =0V,f =1MHz		15	25	pF			
Reverse Transfer Capacitance	C _{rss}			9	15	pF			
SWITCHING CHARACTERISTICS (not	e 3, 4)								
Turn-on delay time	t d(on)			9		ns			
Turn-on rise time	tr	V _{GS} =-4.5V,V _{DS} =-10V,		5.8		ns			
Turn-off delay time	td(off)	I_D =-200mA, R_{GEN} =10 Ω		32.7		ns			
Turn-off fall time	tf			20.3		ns			

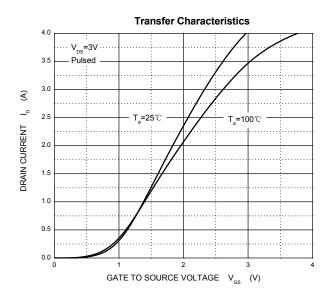
Notes:

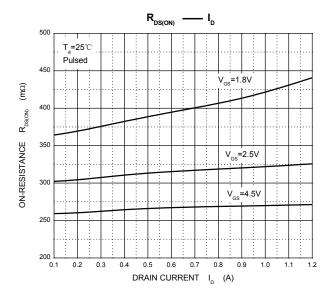
- 1.Surface mounted on FR4 board using the minimum recommended pad size.
- 2. Pulse Test : Pulse width=300µs, duty cycle≤2%.
- 3. Switching characteristics are independent of operating junction temperature.
- 4. Graranted by design, not subject to producting.

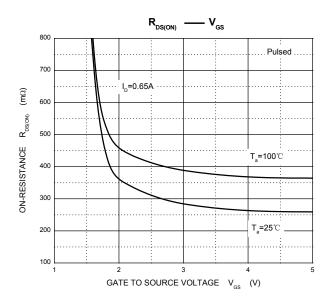
Typical Characteristics

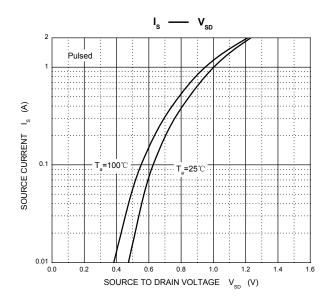
N-Channel MOS

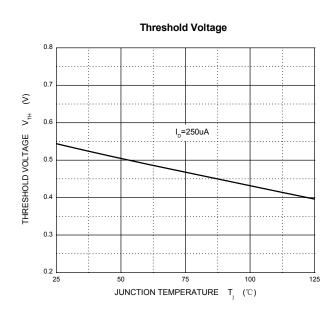






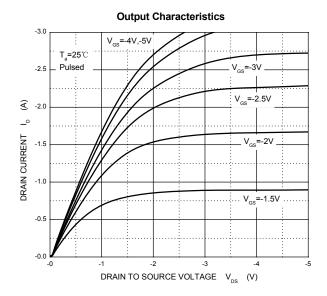


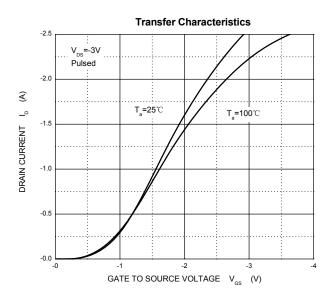


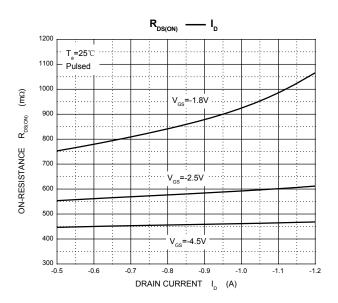


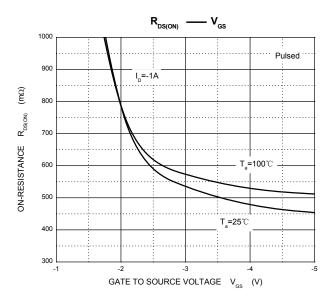
Typical Characteristics

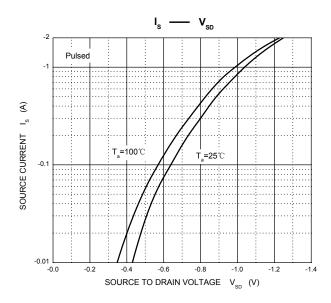
P-Channel MOS

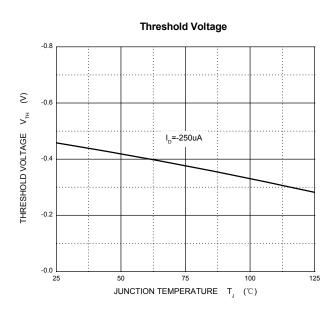




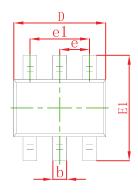


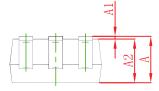


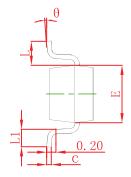




SOT-363 Package Outline Dimensions

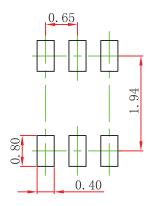






Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.150	0.350	0.006	0.014	
С	0.100	0.150	0.004	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.400	0.085	0.094	
е	0.650) TYP	0.026	S TYP	
e1	1.200	1.400	0.047	0.055	
L	0.525	REF	0.021	REF	
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

SOT-363 Suggested Pad Layout



Note:

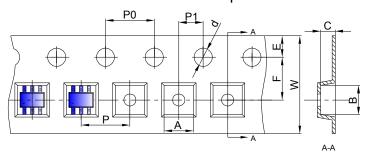
- 1. Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

NOTICE

JCET reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JCET does not assume any liability arising out of the application or use of any product described herein.

SOT-363 Tape and reel

SOT-363 Embossed Carrier Tape

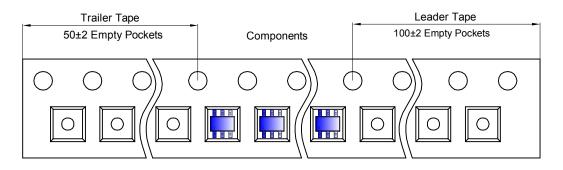


Packaging Description:

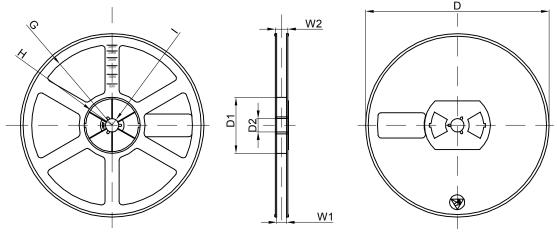
SOT-363 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

	Dimensions are in millimeter									
Pkg type A B C d E F P0 P P1 W								W		
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-363 Tape Leader and Trailer



SOT-363 Reel



Dimensions are in millimeter									
Reel Option	Reel Option D D1 D2 G H I W1 W2								
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30	

REEL	Reel Size	Вох	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	